Designated client product

This product will be discontinued its production in the near term.
And it is provided for customers currently in use only, with a time limit.
It can not be available for your new project. Please select other new or existing products.
For more information, please contact our sales office in your region.

New Japan Radio Co.,Ltd.

www.njr.com

DUAL OPERATIONAL AMPLIFIER

■ GENERAL DESCRIPTION

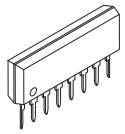
The NJM4560 integrated circuit is a high-gain, wide bandwidth, dual operational amplifier capable of driving 20V peak-to-peak into 400Ω loads. The NJM4560 combines many of the features of the NJM4558 as well as providing the capability of wider bandwidth, and higher slew rate make the NJM4560 ideal for active filters, data and telecommunications, and many instrumentation applications. The availability of the NJM4560 in the surface mounted micro-package allows the NJM4560 to be used in critical applications requiring very high packing densities.

■ PACKAGE OUTLINE

NJM4560D
(DIP8)

NJM4560M
(DMP8)

NJM4560E
(SOP8)

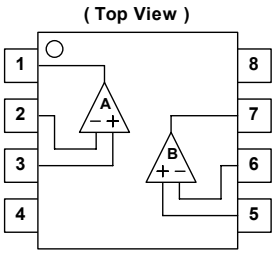


NJM4560L
(SIP8)

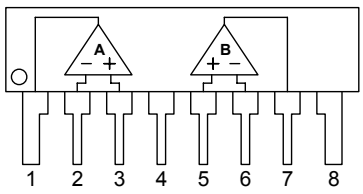
■ FEATURES

- Operating Voltage (±4V~±18V)
- Wide Gain Bandwidth Product (10MHz typ.)
- Slew Rate (4V/μs typ.)
- Package Outline DIP8, DMP8, SIP8, SOP8 JEDEC 150mil
- Bipolar Technology

■ PIN CONFIGURATION



NJM4560D, NJM4560M, NJM4560E

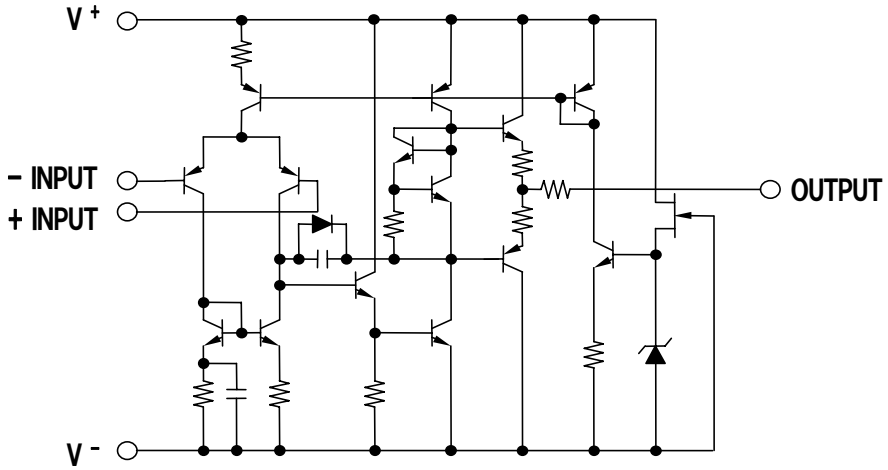


NJM4560L

PIN FUNCTION

1. A OUTPUT
2. A - INPUT
3. A +INPUT
4. V^-
5. B +INPUT
6. B - INPUT
7. B OUTPUT
8. V^+

■ EQUIVALENT CIRCUIT (1/2 Shown)



■ ABSOLUTE MAXIMUM RATINGS

(Ta=25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V^+/V^-	± 18	V
Differential Input Voltage	V_{ID}	± 30	V
Input Voltage	V_{IC}	± 15 (note)	V
Power Dissipation	P_D	(DIP8) 500 (DMP8) 300 (SOP8) 300 (SIP8) 800	mW
Operating Temperature Range	T_{opr}	-40~+85	°C
Storage Temperature Range	T_{stg}	-40~+125	°C

(note) For supply voltage less than ±15V,the absolute maximum input voltage is equal to the supply voltage.

■ ELECTRICAL CHARACTERISTICS

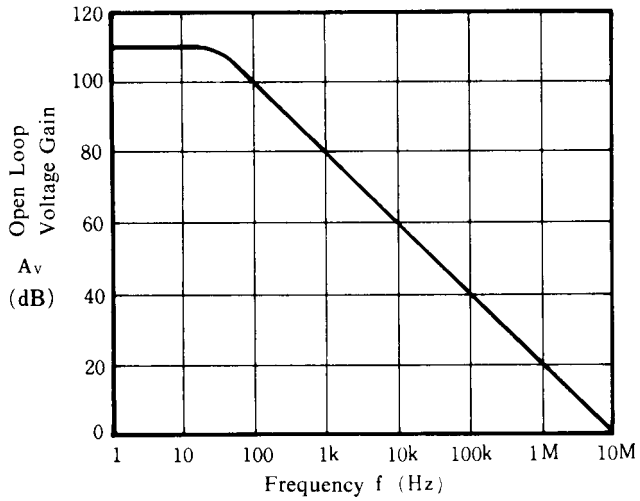
(Ta=25°C,V^+/V^-=±15V)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Input Offset Voltage	V_{IO}	R_S≦10kΩ	-	0.5	6	mV
Input Offset Current	I_{IO}		-	5	200	nA
Input Bias Current	I_B		-	40	500	nA
Input Resistance	R_{IN}		0.3	5	-	MΩ
Large Signal Voltage Gain	A_V	R_L≧2kΩ,V_O=±10V	86	100	-	dB
Maximum Output Voltage Swing 1	V_{OM1}	R_L≧2kΩ	± 12	± 14	-	V
Maximum Output Voltage Swing 2	V_{OM2}	I_O=25mA	± 10	± 11.5	-	V
Input Common Mode Voltage Range	V_{ICM}		± 12	± 14	-	V
Common Mode Rejection Ratio	CMR	R_S≦10kΩ	70	90	-	dB
Supply Voltage Rejection Ratio	SVR	R_S≦10kΩ	76.5	90	-	dB
Operating Current	I_{CC}		-	4.3	5.7	mA
Slew Rate	SR		-	4	-	V/μs
Gain Bandwidth Product	GB		-	10	-	MHz
Equivalent Input Noise Voltage	V_{NI}	RIAA,R_S=2kΩ,30kHz LPF	-	1.2	-	μVrms

■ TYPICAL CHARACTERISTICS

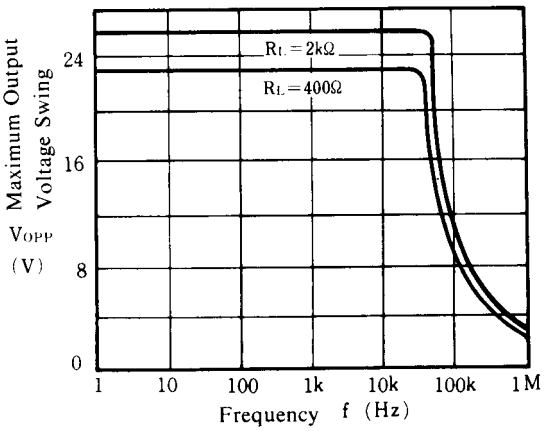
Open Loop Voltage Gain vs. Frequency

($V^+/V^-=\pm15V$, $R_L=2k\Omega$, $Ta=25℃$)



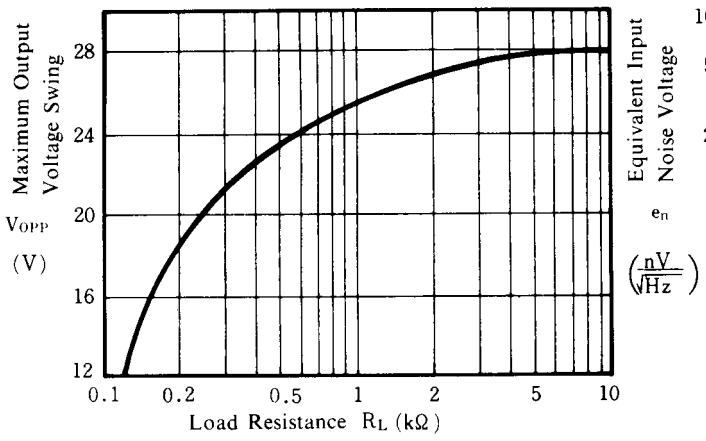
Maximum Output Voltage Swing vs. Frequency

($V^+/V^-=\pm15V$, $Ta=25℃$)



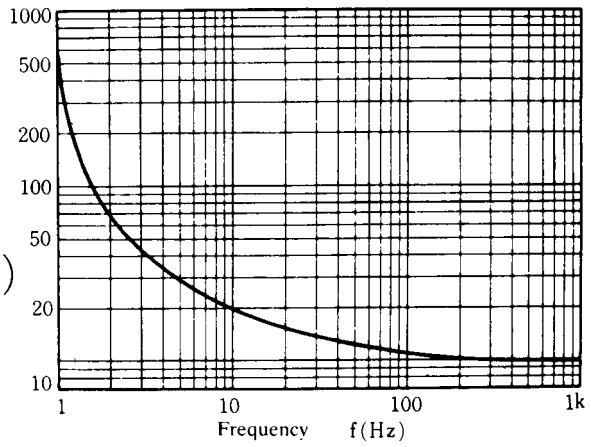
Maximum Output Voltage Swing vs. Load Resistance

($V^+/V^-=\pm15V$, $Ta=25℃$)



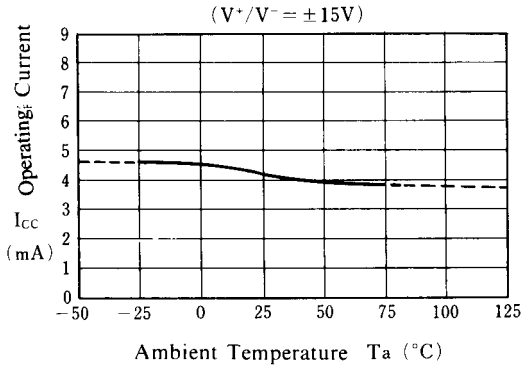
Equivalent Input Noise Voltage vs. Frequency

($V^+/V^-=\pm15V$, $R_S=50\Omega$, $Av=60dB$, $Ta=25℃$)



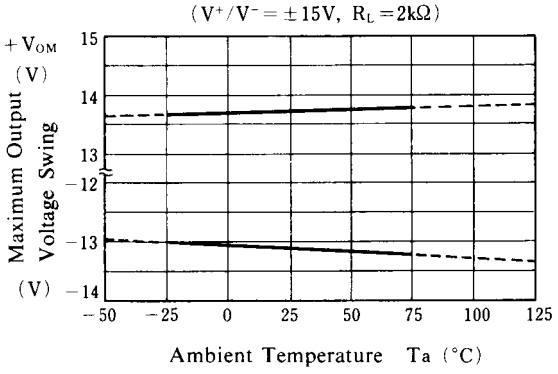
Operating Current vs. Temperature

($V^+/V^-=\pm15V$)



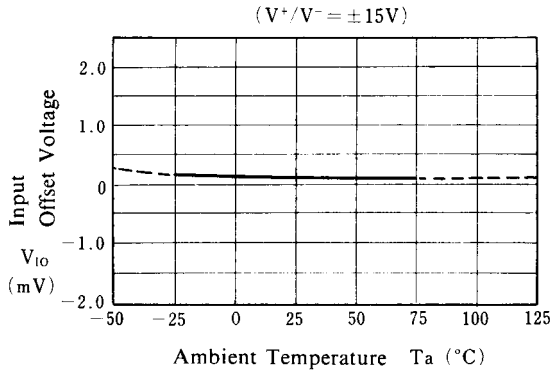
Maximum Output Voltage Swing vs. Temperature

($V^+/V^-=\pm15V$, $R_L=2k\Omega$)

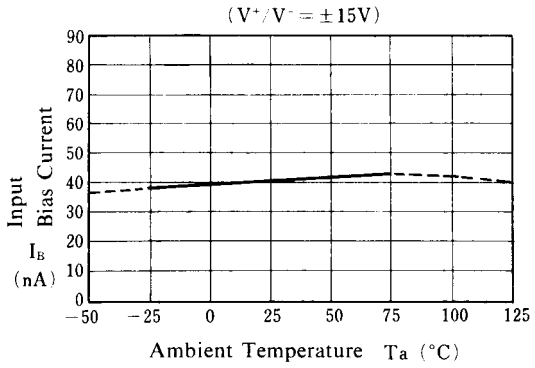


■ TYPICAL CHARACTERISTICS

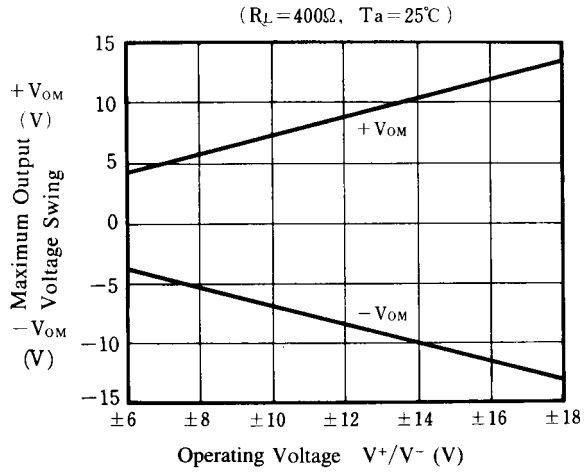
Input Offset Voltage vs. Temperature



Input Bias Current vs. Temperature



Maximum Output Voltage Swing vs. Supply Voltage



Operating Current vs. Operating Voltage